

Microsemi Corp.
The diode experts

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Features

- AXIAL AND SURFACE MOUNT CONFIGURATIONS
- HIGH VOLTAGE WITH ULTRA FAST RECOVERY TIME
- VERY LOW SWITCHING LOSS AT HIGH TEMPERATURE
- LOW CAPACITANCE
- METALLURGICALLY BONDED
- NON-CAVITY GLASS PACKAGE
- SURFACE MOUNT DIODES THERMALLY MATCHED FOR USE ON CERAMIC PRINTED WIRING BOARDS
- AXIAL AND SURFACE MOUNT AVAILABLE AS JANTX AND JANTXV PER MIL-S-19500/590

Maximum Ratings @ 25°C

TYPE NUMBER	REVERSE VOLTAGE	OPERATING CURRENT (Note 1)	OPERATING CURRENT (Note 3)	PEAK FORWARD SURGE CURRENT (Note 2)	$R_{\theta-JL}$ L = .375"	$R_{\theta-JEC}$
1N6626 and US	200	4.0A	2.0A	75A	22°C/W	10°C/W
1N6627 and US	400	4.0A	2.0A	75A	22°C/W	10°C/W
1N6628 and US	600	4.0A	2.0A	75A	22°C/W	10°C/W
1N6629 and US	800	3.0A	1.4A	75A	22°C/W	10°C/W
1N6630 and US	900	3.0A	1.4A	75A	22°C/W	10°C/W
1N6631 and US	1000	2.5A	1.4A	60A	22°C/W	10°C/W

Operating Temperature: -65°C to +175°C.

Storage Temperature: -65°C to +200°C.

Note 1: $T_L = +75^\circ\text{C}$, L = .375 inch for axial parts. Derate linearly at 1.0% / °C for $T_L > +75^\circ\text{C}$. For surface mount devices, US suffix, these currents apply with a maximum end cap temperature of 110°C. Derate linearly at 1.5% / °C above 110°C.

Note 2: Test pulse = 8.3ms, half sine wave.

Note 3: Independent of heatsinking.

Electrical Characteristics @ 25°C

TYPE NUMBER	MINIMUM BREAK-DOWN VOLTAGE V_R $I_R = 50\mu\text{A}$	MAXIMUM FORWARD VOLTAGE V_F @ I_F	MAXIMUM D.C. REVERSE CURRENT I_R @ RATED REVERSE VOLTAGE $T_A = 25^\circ\text{C}$ $T_A = 150^\circ\text{C}$	MAXIMUM REVERSE RECOVERY TIME t_{rr} Note 1	MAXIMUM JUNCTION CAPACITANCE C_j $V_R = 10\text{V}$	PEAK RECOVERY CURRENT $I_{RM}(\text{pF})$ $I_F = 2\text{A}$, 100A/μs	FORWARD RECOVERY VOLTAGE $V_{FRM}(\text{Max.})$ $I_F = 0.5\text{A}$ $t_r = 12\text{ns}$
	V	V @ A	V @ A	μA μA	ns	pf	A V
1N6626 and US	220	1.35V @ 1.2A	1.50V @ 4.0A	2.0 500	30	40	3.5 8
1N6627 and US	440	1.35V @ 1.2A	1.50V @ 4.0A	2.0 500	30	40	3.5 8
1N6628 and US	660	1.35V @ 1.2A	1.50V @ 4.0A	2.0 500	30	40	3.5 8
1N6629 and US	880	1.40V @ 1.0A	1.70V @ 3.0A	2.0 500	50	40	4.2 12
1N6630 and US	990	1.40V @ 1.0A	1.70V @ 3.0A	2.0 500	50	40	4.2 12
1N6631 and US	1100	1.60V @ 1.0A	1.95V @ 2.5A	4.0 600	60	40	5.0 20

NOTE 1: Reverse Recovery Time Test Conditions: $I_F = 0.5\text{A}$, $I_{RM} = 1.0\text{A}$, $I_R(\text{REC}) = 0.25\text{A}$.

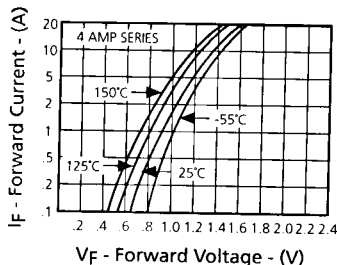


FIGURE 2
Typical Forward Current
vs
Forward Voltage

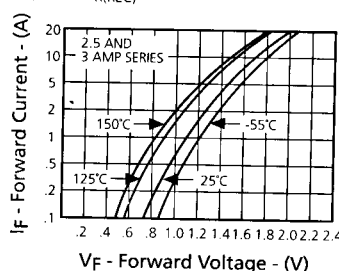


FIGURE 3
Typical Forward Current
vs
Forward Voltage

1N6626 thru 1N6631

ULTRA FAST RECTIFIERS

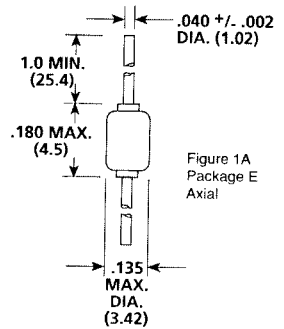


Figure 1A
Package E
Axial

1N6626US thru 1N6631US

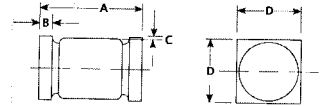


Figure 1B
Package E
Surface
Mount

	Inch	MIN.	MAX.	mm	MIN.	MAX.
A	.205	.225		5.080	5.350	
B	.019	.028		0.483	0.711	
C	.003			0.076		
D	.137	.142		3.480	3.759	

Mechanical Characteristics

AXIAL LEADED DEVICES

CASE: Voidless Hermetically Sealed Hard Glass.

LEAD MATERIAL: Solder Dipped Copper.

MARKING: Body Painted, Alpha Numeric.

POLARITY: Cathode Band.

SURFACE MOUNT DEVICES

CASE: Voidless Hermetically Sealed Hard Glass.

END CAP MATERIAL: Solid Silver.

END CAP CONFIGURATION: Square.

POLARITY: Cathode Dot on End Cap.

1N6626 thru 1N6631 AXIAL LEADED **1N6626US thru 1N6631US SURFACE MOUNT**

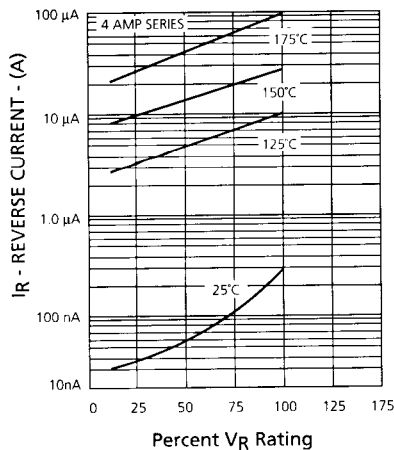


FIGURE 4
 Typical Reverse Current vs
 Applied Reverse Voltage

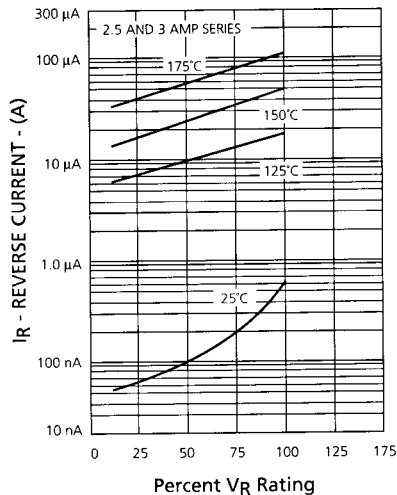


FIGURE 5
 Typical Reverse Current vs
 Applied Reverse Voltage

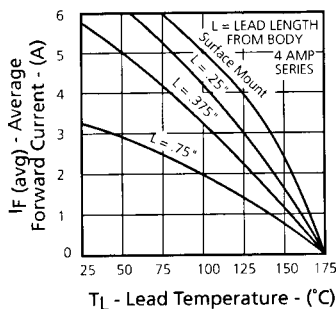


FIGURE 6
 Average Forward Current vs
 Lead Temperature (50% Duty Cycle, Square Wave)

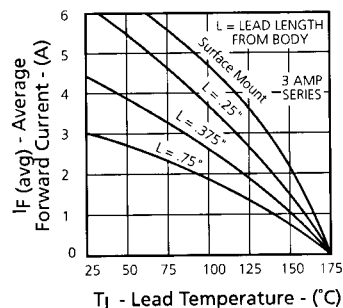


FIGURE 7
 Average Forward Current vs
 Lead Temperature (50% Duty Cycle, Square Wave)

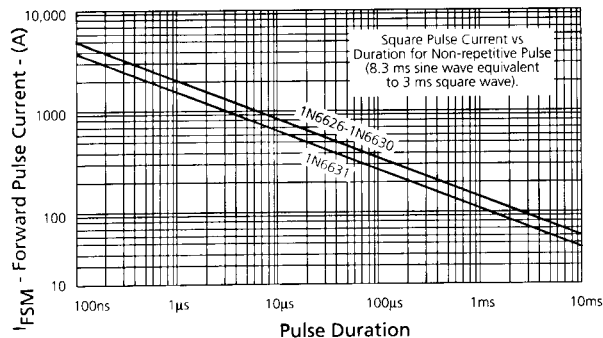


FIGURE 8
 Forward Pulse Current vs
 Pulse Duration

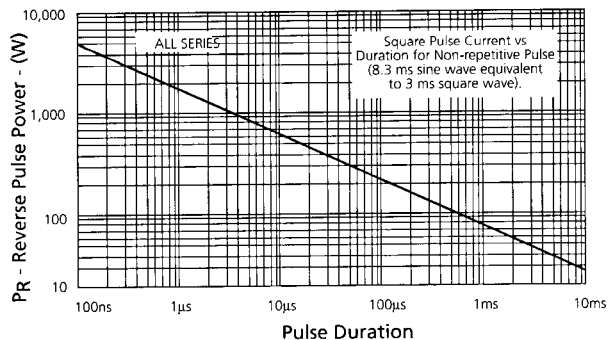


FIGURE 9
 Reverse Pulse Power vs
 Pulse Duration

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